

Precision 8-Ch/Dual 4-Ch/Triple 2-Ch Low Voltage Analog Switches/Multiplexers

DESCRIPTION

The DG9051/9052/9053 are low-voltage monolithic CMOS analog switches and multiplexers. DG9051 is an 8-channel multiplexer; DG9052 is a dual 4-channel multiplexer; and DG9053 is a triple single-pole/double throw (SPDT) switch.

They are designed to operate from a +2.7 to +12-V single supply or ± 2.7 to ± 6 -V dual power supplies. All control logic inputs have guaranteed 2-V logic high/0.8-V logic low when operating from a single 5 V or dual ± 5 -V supplies, and 2.4-V logic high/0.8-V logic low when $V_{+} = 12$ V.

Built on Vishay Siliconix's proprietary high-density process, the DG9051/9052/9053 offer the advantage of bi-directional signal, rail to rail analog signal handling.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the Lead (Pb)-Free device terminations. For analog switching products manufactured with 100 % matte tin device termination, the Lead (Pb)-Free "E3" suffix is being used as a designator.

FEATURES

- 2.7 to 12-V Single Supply or ± 2.7 to ± 6 -V Dual Supply Operation
- Guaranteed Ron Matching
- Low Voltage CMOS Logic Compatible



RoHS
COMPLIANT

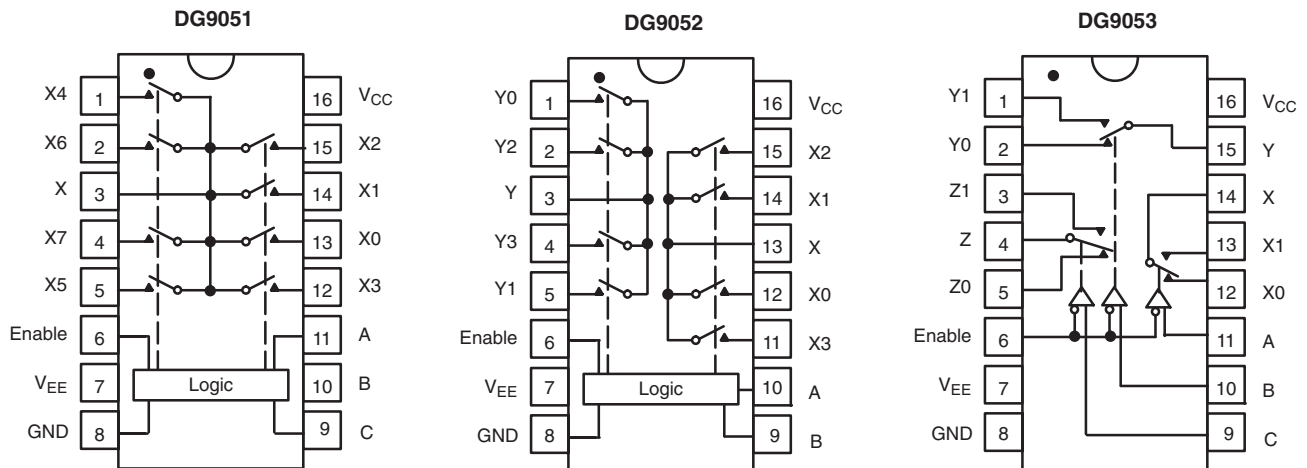
BENEFITS

- Wide Operation Voltage Range
- Pin Compatible with 74HC4051/2/5
- Guaranteed Low Leakage

APPLICATIONS

- Battery Powered Equipment
- Test Process Equipment
- Communication Systems
- A/V and Mixed Signal Routing
- Automotive

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



ORDERING INFORMATION

Temp Range	Package	Part Number
-40 to 85°C	TSSOP-16	DG9051DQ-T1-E3
		DG9052DQ-T1-E3
		DG9053DQ-T1-E3

The information shown here is a preliminary product proposal, not a commercial product data sheet. Siliconix is not committed to produce this or any similar product. This information should not be used for design purposes, nor construed as an offer to furnish or sell such products

TRUTH TABLE						
Enable Input	Select Inputs			On Switches		
	C*	B	A	DG9051	DG9052	DG9053
H	X	X	X	All switches open	All switches open	All switches open
L	L	L	L	X – X0	X – X0, Y – Y0	X – X0, Y – Y0, Z – Z0
L	L	L	H	X – X1	X – X1, Y – Y1	X – X1, Y – Y0, Z – Z0
L	L	H	L	X – X2	X – X2, Y – Y2	X – X0, Y – Y1, Z – Z0
L	L	H	H	X – X3	X – X3, Y – Y3	X – X1, Y – Y1, Z – Z0
L	H	L	L	X – X4	X – X0, Y – Y0	X – X0, Y – Y0, Z – Z1
L	H	L	H	X – X5	X – X1, Y – Y1	X – X1, Y – Y0, Z – Z1
L	H	H	L	X – X6	X – X2, Y – Y2	X – X0, Y – Y1, Z – Z1
L	H	H	H	X – X7	X – X3, Y – Y3	X – X1, Y – Y1, Z – Z1

X = Don't care

ABSOLUTE MAXIMUM RATINGS $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted				
Parameter		Symbol	Limit	Unit
Voltage Referenced to V–	V+		13.5	V
	GND		7	
Digital Inputs ^a	V _S , V _D		(V–) –0.3 to (V+) +0.3	
Current (Any Terminal Except S or D)			30	mA
Continuous Current, S or D			100	
Peak Current, S or D (Pulsed at 1 ms, 10 % Duty Cycle Max)			200	
Package Solder Reflow Conditions ^b	IR/Convection		260	$^{\circ}\text{C}$
Storage Temperature			–65 to 150	
Power Dissipation (Packages) ^c	$T_A = 70\text{ }^{\circ}\text{C}$, TSSOP-16 ^d		925	mW

**SPECIFICATIONS (SINGLE SUPPLY 12 V)**

Parameter	Symbol	Test Condition Otherwise Unless Specified V+ = 12 V, ±10 %, V− = 0 V V _A , V _{EN} = 0.8 V or 2.4 V ^f	Temp ^b	Limits −40 to 85°C			Unit
				Min ^c	Typ ^d	Max ^c	
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	0		12	V
On-Resistance	r _{ON}	V _D = 3.5 V, I _S = 1 mA Sequence Each Switch On	Room Full		30	40 50	Ω
r _{ON} Match Between Channels ^g	Δr _{ON}	V _D = 3.5 V, I _S = 1 mA	Room			5	
Switch Off Leakage Current	I _{S(off)}	V _{EN} = 2.4 V, V _D = 11 V or 1 V, V _S = 1 V or 11 V	Room Full	−1 −20		1 20	nA
	I _{D(off)}		Room Full	−1 −20		1 20	
Channel On Leakage Current	I _{D(on)}	V _{EN} = 0 V, V _S = V _D = 1 V or 11 V	Room Full	−2 −10		2 10	
Digital Control							
Logic High Input Voltage	V _{INH}		Full	2.4			V
Logic Low Input Voltage	V _{INL}		Full			0.8	
Input Current	I _{IN}	V _{AX} = V _{EN} = 2.4 V or 0.8 V	Full	−1		1	μA
Dynamic Characteristics							
Transition Time	t _{TRANS}	V _{NO} /V _{NC} = 8 V/0 V, 0 V/8 V R _L = 300 Ω, C _L = 35 pF	Room Full		26	35 55	ns
Break-Before-Make Time	t _{BBM}	V _{X,Y,Z} = 5 V, V _S = 0 V, R _L = 306 Ω, C _L = 35 pF	Room Full	3	10		
Enable Turn-On Time	t _{ON(EN)}		Room Full		20	35 45	
Enable Turn-Off Time	t _{OFF(EN)}		Room Full		16	30 40	
Charge Injection ^e	Q	C _L = 1 nF, V _{GEN} = 0 V, R _{GEN} = 0 Ω	Room		38		pC
Off-Isolation ^{e,h}	OIRR	f = 1 MHz, R _L = 50 Ω	Room		−78		dB
Crosstalk ^e	X _{TALK}		Room		−83		
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz, V _S = 0 V, V _{EN} = 2.4 V	Room		4		pF
Drain Off Capacitance ^e	C _{D(off)}	f = 1 MHz, V _D = 0 V, V _{EN} = 2.4 V	Room		8		
Drain On Capacitance ^e	C _{D(on)}	f = 1 MHz, V _D = 0 V, V _{EN} = 0 V	Room		15		
Power Supply							
Power Supply Current	I+	V _{EN} = V _A = 0 V or V+	Room			1.0	μA

SPECIFICATIONS (DUAL SUPPLY V+ = 5 V, V- = -5 V)							
Parameter	Symbol	Test Condition Otherwise Unless Specified V+ = 5 V, V- = -5 V ±10 % VA, VEN = 0.8 V or 2.0 V ^f	Temp ^b	Limits -40 to 85°C			Unit
				Min ^c	Typ ^d	Max ^c	
Analog Switch							
Analog Signal Range ^e	VANALOG		Full	-5		5	V
On-Resistance	rON	V+ = 4.5 V, V- = -4.5 V, VD = ±3 V, IS = 1 mA Sequence Each Switch On	Room Full		35	55 60	Ω
rON Match Between Channels ^g	ΔrON		Room			5	
On-Resistance Flatness ⁱ	rON Flatness	V+ = 4.5 V, V- = -4.5 V, VD = ±3.0 V, IS = 1 mA	Room		7	10	
Switch Off Leakage Current ^a	IS(off)	V+ = 5.5 V, V- = -5.5 V VEN = 2.0 V, VD = ±4.5 V, VS = ±4.5 V	Room Full	-1 -20		1 20	nA
	ID(off)		Room Full	-1 -20		1 20	
Channel On Leakage Current ^a	ID(on)	V+ = 5.5 V, V- = -5.5 V VEN = 0 V, VD = ±4.5 V, VS = ±4.5 V	Room Full	-2 -10		2 10	
Digital Control							
Logic High Input Voltage	VINH		Full	2.0			V
Logic Low Input Voltage	VINL		Full			0.8	
Input Current ^a	IIN	VAX = VEN = 2.0 V or 0.8 V	Full	-1		1	μA
Dynamic Characteristics							
Transition Time ^e	tTRANS	V+ = 4.5 V, V- = -4.5 V VNO/NC = ±3 V, RL = 300 Ω, CL = 35 pF	Room Full		35	50 65	ns
Break-Before-Make Time ^e	tBBM	VX,Y,Z = +/-3 V, VS = 0 V, RL = 300 Ω, CL = 35 pF	Room Full	5	12		
Enable Turn-On Time ^e	tON(EN)		Room Full		38	55 70	
Enable Turn-Off Time ^e	tOFF(EN)		Room Full		22	35 50	
Source Off Capacitance ^e	CS(off)	f = 1 MHz, VS = 0 V, VEN = 2.0 V	Room		5		pF
Drain Off Capacitance ^e	CD(off)	f = 1 MHz, VD = 0 V, VEN = 2.0 V	Room		9		
Drain On Capacitance ^e	CD(on)	f = 1 MHz, VD = 0 V, VEN = 0 V	Room		13		
Power Supply							
Power Supply Current	I+	VEN = VA = 0 V or V+	Room			1.0	μA
	I-		Room	-1.0			

**SPECIFICATIONS (SINGLE SUPPLY 5 V)**

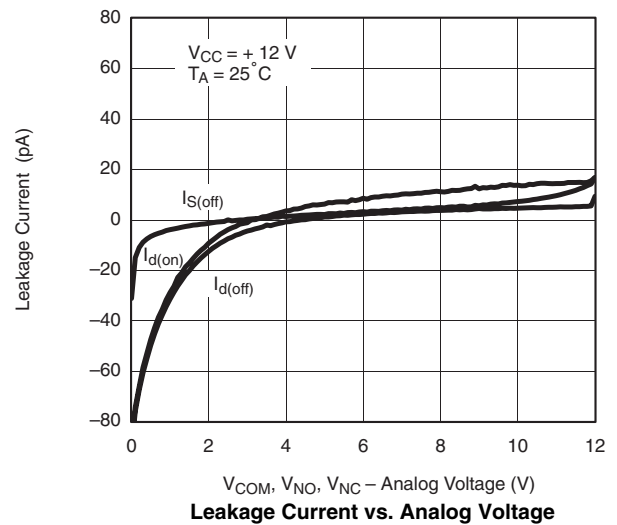
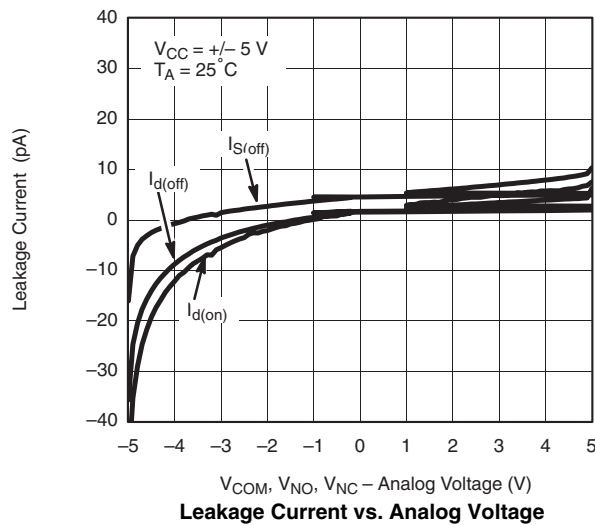
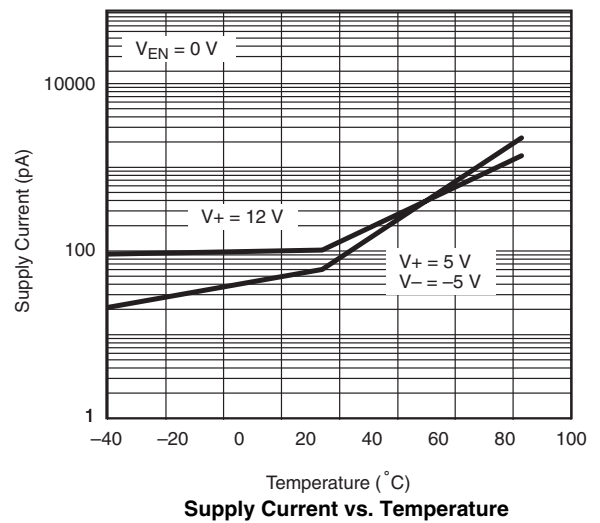
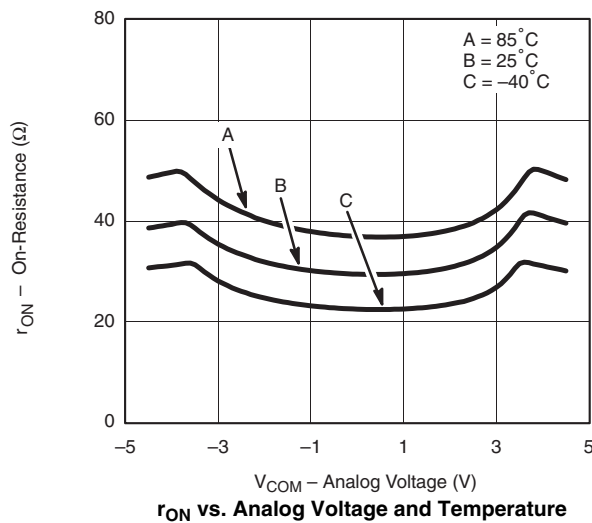
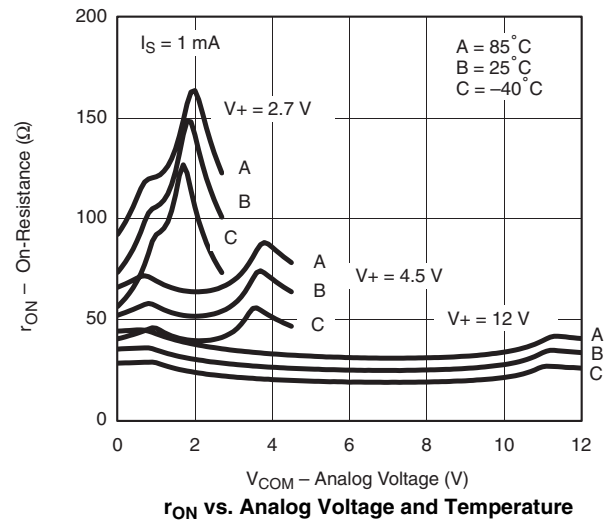
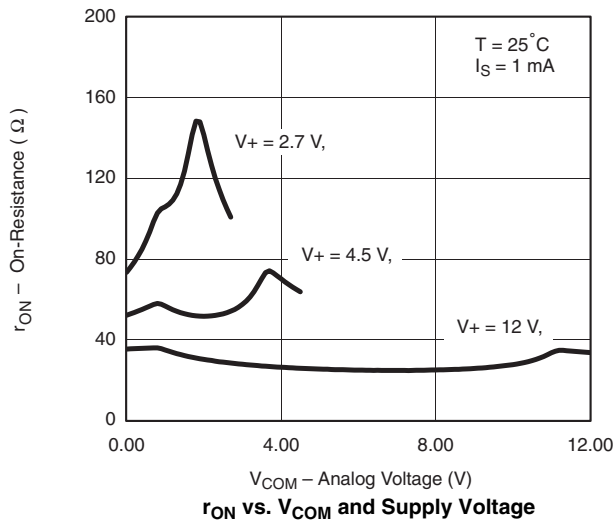
Parameter	Symbol	Test Condition Otherwise Unless Specified V ₊ = 5 V, ±10 %, V _– = 0 V V _A , V _{EN} = 0.8 V or 2.0 V ^f	Temp ^b	Limits –40 to 85°C			Unit
				Min ^c	Typ ^d	Max ^c	
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	0		5	V
On-Resistance	r _{ON}	V ₊ = 4.5 V, V _D or V _S = 3 V or 3.5 V, I _S = 1 mA	Room Full		80	100 120	Ω
r _{ON} Match Between Channels ^g	Δr _{ON}	V ₊ = 4.5 V, V _D = 3 V, I _S = 1 mA	Room			8.0	
Switch Off Leakage Current ^a	I _{S(off)}	V ₊ = 5.5 V, V _{EN} = 2 V V _S = 1 V or 4.5 V, V _D = 4.5 V or 1 V	Room Full	–1 –20		1 20	nA
	I _{D(off)}		Room Full	–1 –20		1 20	
Channel On Leakage Current ^a	I _{D(on)}	V ₊ = 5.5 V, V _{EN} = 0 V V _D = V _S = 1 V or 4.5 V	Room Full	–2 –10		2 10	
Digital Control							
Logic High Input Voltage	V _{INH}		Full	2.0			V
Logic Low Input Voltage	V _{INL}		Full			0.8	
Input Current ^a	I _{IN}	V _{AX} = V _{EN} = 2.0 V or 0.8 V	Full	–1		1	μA
Dynamic Characteristics							
Transition Time	t _{TRANS}	V ₊ = 4.5 V, V _– = 0 V, V _{NO / NC} = 3 V / 0 V, 0 V / 3 V, R _L = 300 Ω, C _L = 35 pF	Room		40		ns
Break-Before-Make Time	t _{BBM}	V ₊ = 4.5 V, V _{X,Y,Z} = 3 V, V _S = 0 V, R _L = 300 Ω, C _L = 35 pF	Room		15		
Enable Turn-On Time	t _{ON(EN)}		Room		40		
Enable Turn-Off Time	t _{OFF(EN)}		Room		20		
Charge Injection ^e	Q	C _L = 1 nF, V _{GEN} = 0 V, R _{GEN} = 0 Ω	Room		20		pC
Off-Isolation ^{e,h}	OIRR	f = 1 MHz, R _L = 50 Ω	Room		–79		dB
Crosstalk ^e	X _{TALK}		Room		–83		
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz, V _S = 0 V, V _{EN} = 0 V	Room		4		pF
Drain Off Capacitance ^e	C _{D(off)}	f = 1 MHz, V _D = 0 V, V _{EN} = 2.0 V	Room		8		
Drain On Capacitance ^e	C _{D(on)}	f = 1 MHz, V _D = 0 V, V _{EN} = 0 V	Room		15		
Power Supply							
Power Supply Current	I ₊	V _{EN} = V _A = 0 V or V ₊	Room			1.0	μA

SPECIFICATIONS (SINGLE SUPPLY 3 V)								
Parameter	Symbol	Test Condition Otherwise Unless Specified V+ = 3 V, ±10 %, V– = 0 V V _{EN} = 0.4 V or 2.0 V	Temp ^b	Limits –40 to 85°C			Unit	
				Min ^c	Typ ^d	Max ^c		
Analog Switch								
Analog Signal Range ^e	V _{ANALOG}		Full	0		3	V	
On-Resistance	r _{ON}	V+ = 2.7 V, V _D = 1.5 V, I _S = 0.1 mA	Room		130		Ω	
r _{ON} Match Between Channels ^g	Δr _{ON}	V+ = 2.7 V, V _D = 1.5 V, I _S = 0.1 mA	Room			12		
Switch Off Leakage Current ^a	I _{S(off)}	V+ = 3.3 V, V _{EN} = 2.0 V V _S = 3 or 0.3 V, V _D = 0.3 or 3 V	Room Full	–1 –20		1 20	nA	
	I _{D(off)}		Room Full	–1 –20		1 20		
Channel On Leakage Current ^a	I _{D(on)}	V+ = 3.3 V, V _{EN} = 0 V V _S = 3 or 0.3 V, V _D = 0.3 or 3 V	Room Full	–2 –10		2 10		
Digital Control								
Logic High Input Voltage	V _{INH}		Full	2.0			V	
Logic Low Input Voltage	V _{INL}		Full			0.4		
Input Current ^a	I _{IN}	V _{AX} = V _{EN} = 2.0 V or 0.4 V	Full	–1		1	μA	
Dynamic Characteristics								
Transition Time	t _{TRANS}	V+ = 2.7 V, V _{NO/NC} = 1.5 V/0 V, 0 V/1.5 V R _L = 300 Ω, C _L = 35 pF	Room		80		ns	
Break-Before-Make Time	t _{BBM}	V+ = 2.7 V, V _{X,Y,Z} = 1.5 V, V _S = 0 V, R _L = 300 Ω, C _L = 35 pF	Room Full	5	25			
Enable Turn-On Time	t _{ON(EN)}		Room			90		
Enable Turn-Off Time	t _{OFF(EN)}		Room			30		
Charge Injection ^e	Q	C _L = 1 nF, V _{GEN} = 0 V, R _{GEN} = 0 Ω	Room		9		pC	
Off-Isolation ^{e,h}	OIRR	f = 1 MHz, R _L = 50 Ω	Room		–78		dB	
Crosstalk ^e	X _{TALK}		Room		–83			
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz, V _S = 0 V, V _{EN} = 1.8 V	Room		5		pF	
Drain Off Capacitance ^e	C _{D(off)}	f = 1 MHz, V _D = 0 V, V _{EN} = 1.8 V	Room		10			
Drain On Capacitance ^e	C _{D(on)}	f = 1 MHz, V _D = 0 V, V _{EN} = 0 V	Room		15			
Power Supply								
Power Supply Current	I+	V _{EN} = V _A = 0 V or V+	Room			1.0	μA	

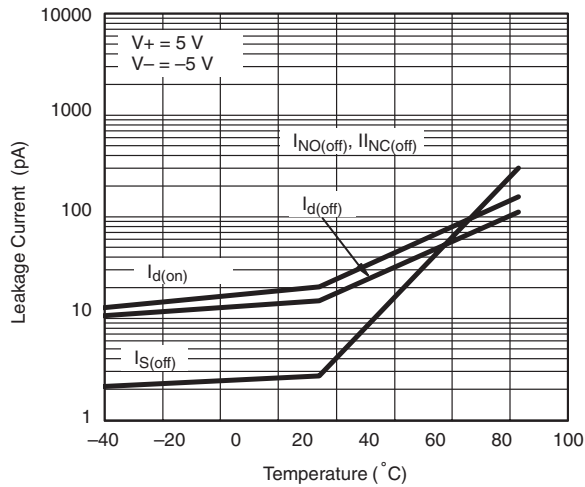
Notes

- Leakage parameters are guaranteed by worst case test condition and not subject to production test.
- Room = 25°C, Full = as determined by the operating temperature suffix.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- Guaranteed by design, not subject to production test.
- V_{IN} = input voltage to perform proper function.
- $\Delta r_{\text{DON}} = r_{\text{DON Max}} - r_{\text{DON Min}}$.
- Worst case isolation occurs on Channel 4 due to proximity to the drain pin.
- r_{DON} flatness is measured as the difference between the minimum and maximum measured values across a defined Analog signal.

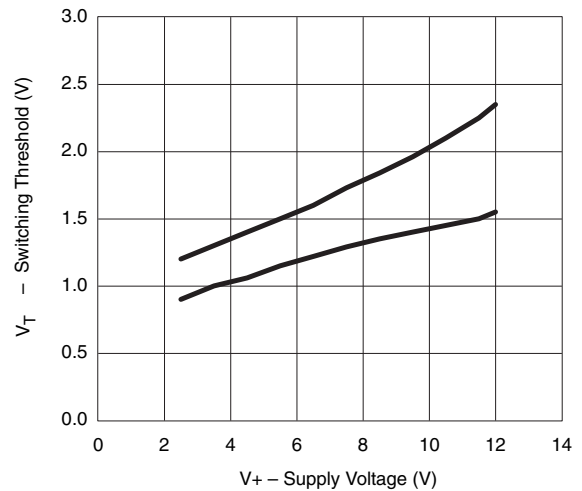
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, unless otherwise noted


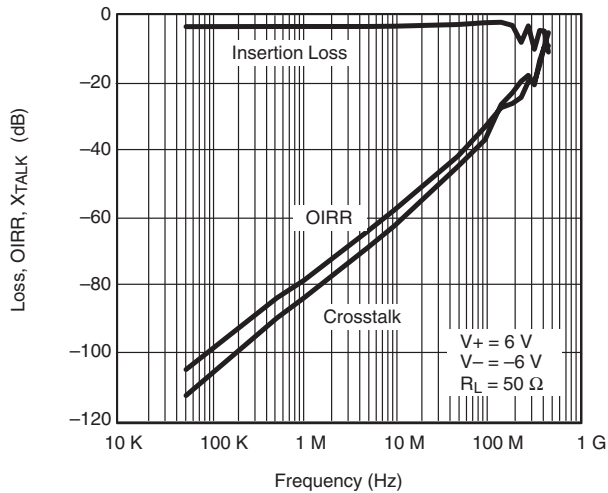
TYPICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, unless otherwise noted



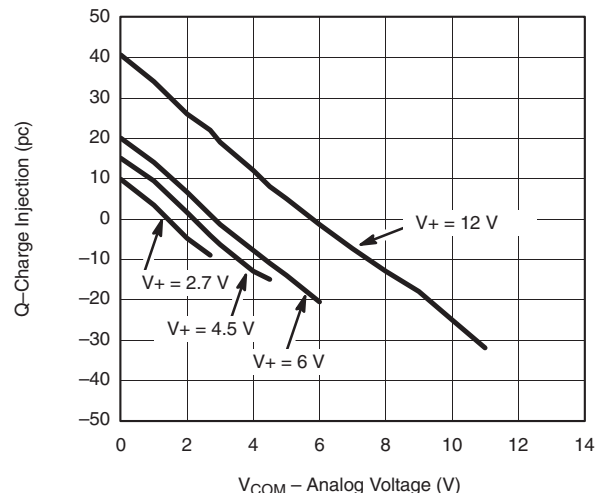
Leakage Current vs. Temperature



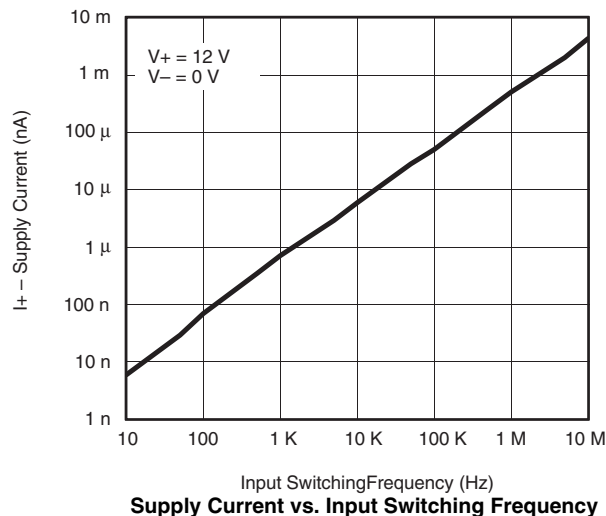
Switching Threshold vs. Supply Voltage



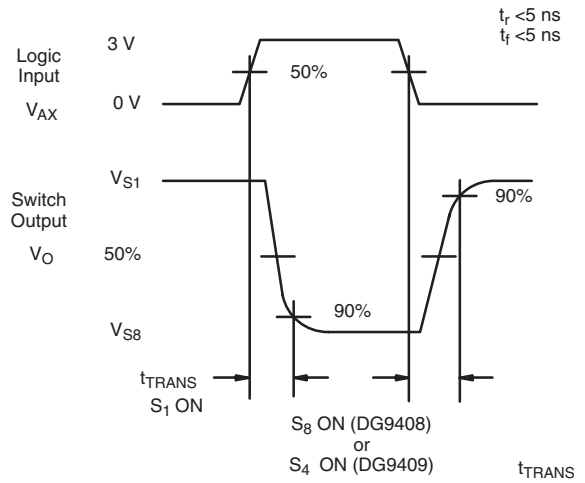
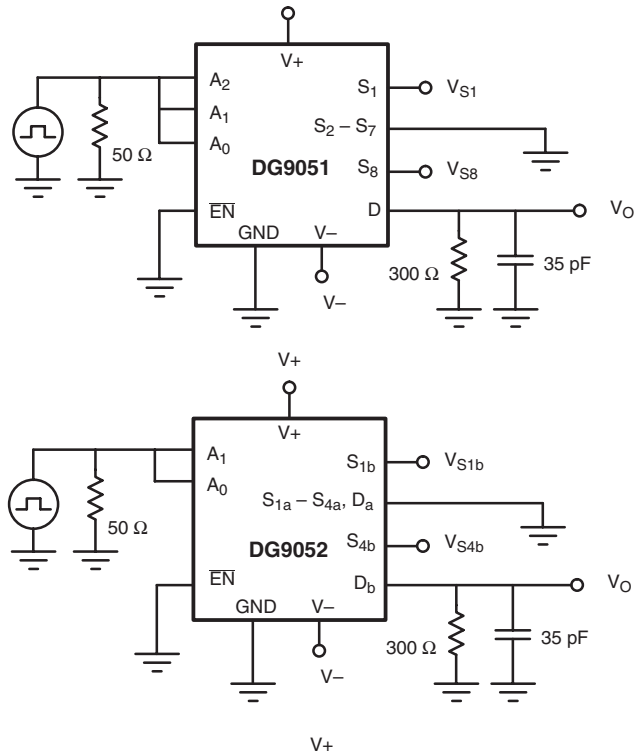
Insertion Loss, Off-Isolation Crosstalk vs. Frequency



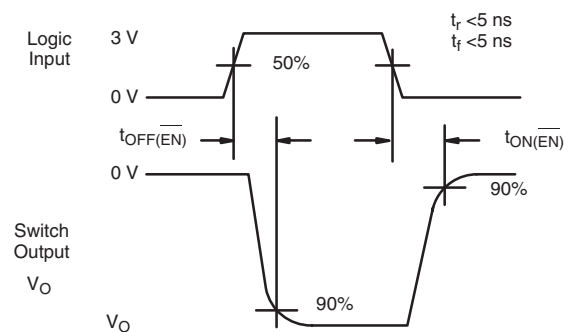
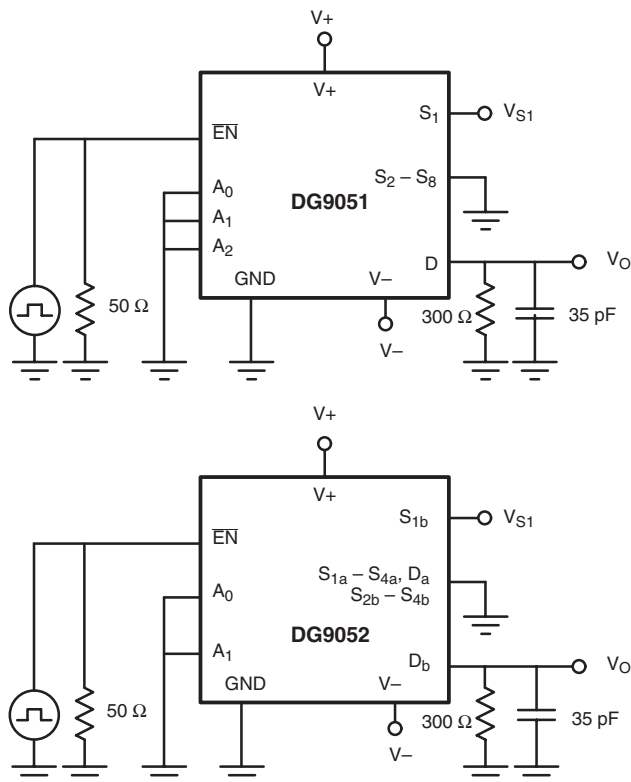
Charge Injection vs. Analog Voltage



Supply Current vs. Input Switching Frequency

TEST CIRCUITS


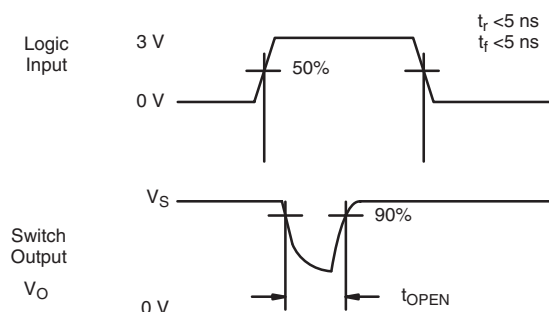
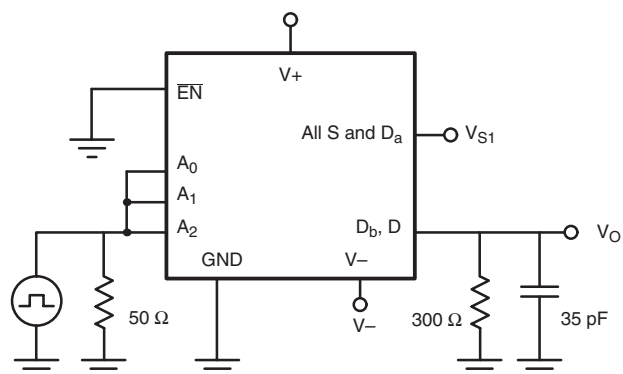
Return to Specifications:
 Single Supply 12 V
 Dual Supply $V_+ = 5\text{ V}$, $V_- = -5\text{ V}$
 Single Supply 5 V
 Single Supply 3 V

Figure 1. Transition Time


Return to Specifications:
 Single Supply 12 V
 Dual Supply $V_+ = 5\text{ V}$, $V_- = -5\text{ V}$
 Single Supply 5 V
 Single Supply 3 V

Figure 2. Enable Switching Time

TEST CIRCUITS



Return to Specifications:
 Single Supply 12 V
 Dual Supply $V_+ = 5\text{ V}$, $V_- = -5\text{ V}$
 Single Supply 5 V
 Single Supply 3 V

Figure 3. Break-Before-Make Interval

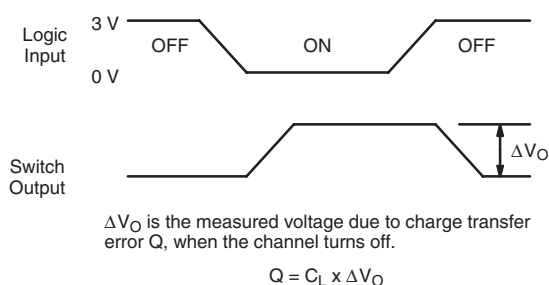
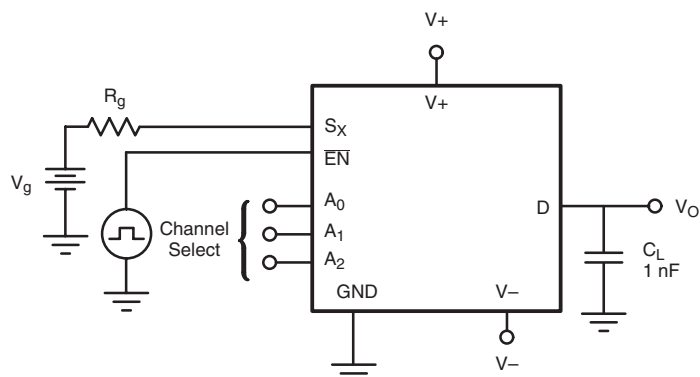


Figure 4. Charge Injection

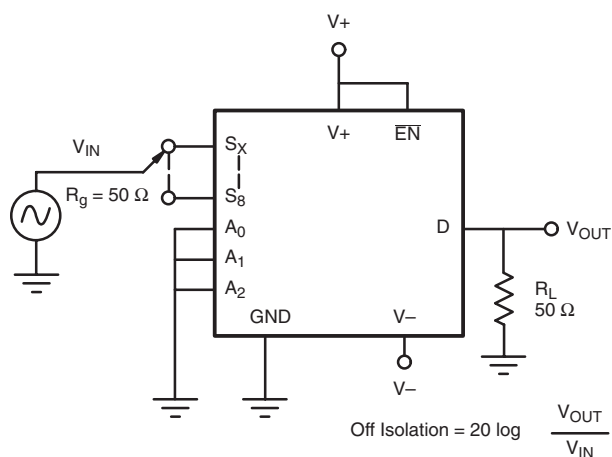


Figure 5. Off Isolation

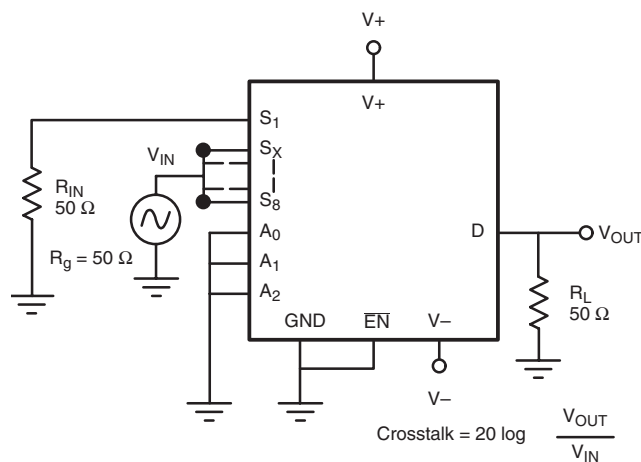


Figure 6. Crosstalk

TEST CIRCUITS

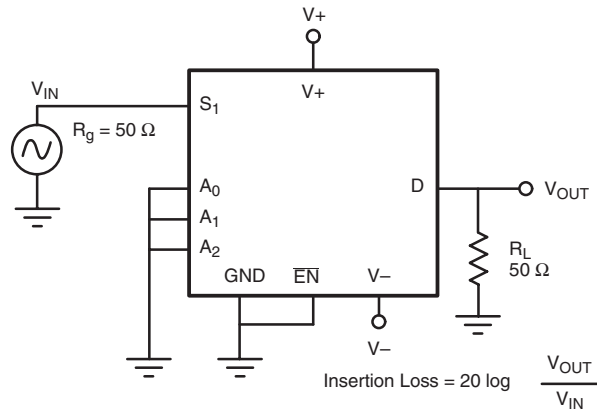


Figure 7. Insertion Loss

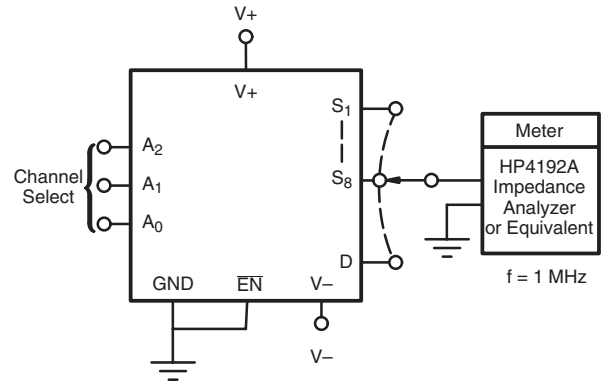


Figure 8. Source Drain Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <http://www.vishay.com/ppg?73410>.



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